HONGLITAI PHOTOELECTRICITY CO.,LTD

DATA SHEET

●DEVICE NUMBER：HPC-816S

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2014-11-14	1.0	1.0	1.0	1.0	1.0	1.0						Original Released

鸿利泰光电科技有限公司

HONGLITAI PHOTOELECTRICITY CO.,LTD

深圳市宝安沙井街道芙蓉工业区芙蓉 **6** 路 **122** 号

Tel:0755-29504006

Fax: 0755-29504016

www.hlt-otpo.com

APPROVED	DRAWER
邱丽红	刘钱兵

● Features:

1. Current transfer ratio (CTR: MIN. 50% at I_F=5mA, V_{CE}=5V)
2. High input-output isolation voltage (V_{ISO}=5,000Vrms)
3. Response time (tr: TYP. 4μs at V_{CE}=2V, I_C=2mA, R_L=100 Ω)
4. This product doesn't contain restriction substance, comply RoHS standard

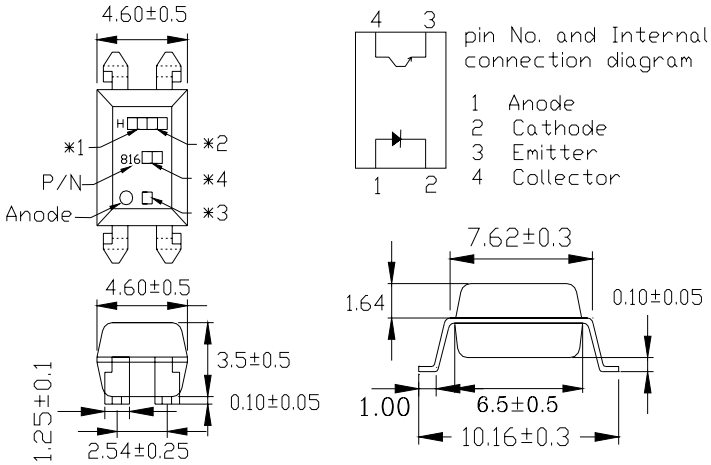
● Description

1. The HPC-816S series are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor
2. The lead pitch is 2.54mm

● Applications:

1. Computer terminals.
2. System appliances, measuring instruments.
3. Registers, copiers, automatic vending machines.
4. Electric home appliances, such as fan heaters, etc.
5. Signal transmission between circuits of different potentials and impedances.

● Outline Dimensions



●NOTES：

*1. Year date code.
*2. 2-digit work week.
*3. Factory identification mark shall be marked.
(T：Taiwan, G：China)
*4. Rank shall be or shall not be marked.

●Absolute Maximum Ratings (Ta=25℃)

Parameter		Symbol	Rating	Unit
INPUT	Forward Current	I_F	50	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	70	mW
OUTPUT	Collector-Emitter Voltage	V_{CEO}	35	V
	Emitter- Collector Voltage	V_{ECO}	6	
	Collector Current	I_C	50	mA
	Collector Power Dissipation	P_C	150	mW
Total Power Dissipation		P_{tot}	200	mW
*1 Isolation Voltage		V_{iso}	5,000	Vrms
Rated impulse isolation voltage		V_{IOTM}	6,000	V
Rated repetitive peak isolation voltage		V_{IORM}	630	V
Operating Temperature		T_{opr}	-30 to + 110	℃
Storage Temperature		T_{stg}	-55 to + 125	
*2 Soldering Temperature		Tsol	260	

*1. AC For minute, R.H. =40~60%
Isolation voltage shall be measured using the following method.
(1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
(2) The isolation voltage tester with zero-cross circuit shall be used.
(3) The waveform of applied voltage shall be a sine wave.
*2. For 10 Seconds

●Electro-Optical Characteristics (Ta=25℃)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit.
INPUT	Forward Voltage	V_F	I_F=20mA	1.0	1.2	1.4	V
	Reverse Current	I_R	V_R=6V	---	---	10	μA
	Terminal Capacitance	C_t	V=0, f=1KHz	---	30	250	pF
OUTPUT	Collector Dark Current	I_{CEO}	V_{CE}=20V, I_F=0	---	---	100	nA
	Collector-Emitter Breakdown Voltage	BV_{CEO}	I_C=0.1mA I_F=0	80	---	---	V
	Emitter-Collector Breakdown Voltage	BV_{ECO}	I_E=10μA I_F=0	6	---	---	V
TRANSFER CHARACTERISTICS	Collector Current	I_c	I_F=5mA	2.5	---	30	mA
	*1 Current Transfer Ratio	CTR	V_{CE}=5V	300	---	600	%
	Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_F=20mA I_C= 1mA	---	---	0.2	V
	Isolation Resistance	R_{iso}	DC500V 40~60%R.H.	5×10^{10}	1×10^{11}	---	Ω
	Floating Capacitance	C_f	V=0, f=1MHz	---	0.6	1	pF
	Cut-Off Frequency	f_c	V_{CE}=5V, I_C=2mA R_L=100Ω, -3dB	---	80	---	kHz
	Response Time(Rise)	t_r	V_{CE}=2V, I_C=2mA R_L=100Ω	---	4	18	μs
	Response Time(Fall)	t_f		---	3	18	μs

*1 CTR= I_C / I_F × 100%

●RANK TABLE OF CURRENT TRANSFER RATIO(CTR)

RANK MARK.	Min. (%)	Max. (%)
L	50	100
A	80	160
B	130	260
C	200	400
D	300	600
L or A or B or C or D	50	600

Notes:

1. Conditions: I_F=5mA, V_{CE}=5V, Ta=25℃.

● CHARACTERISTICS CURVES

Fig.1 Forword Current
Ambient Temperature

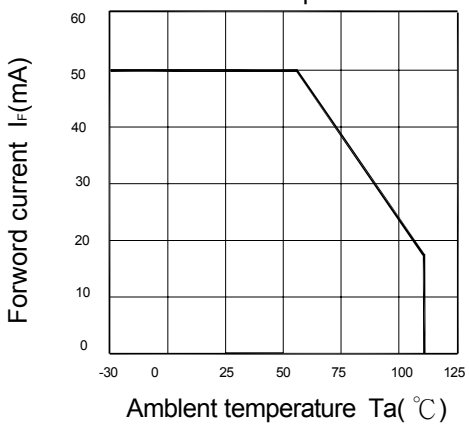


Fig.2 Collector Power Dissiption
vs. Ambient Temperature

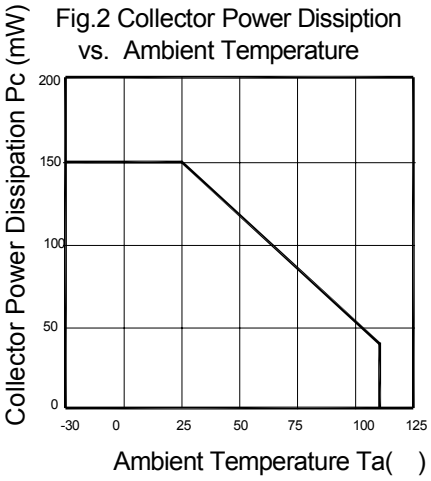


Fig.3 Collector-emitter Saturation
Voltage vs. Forward Current

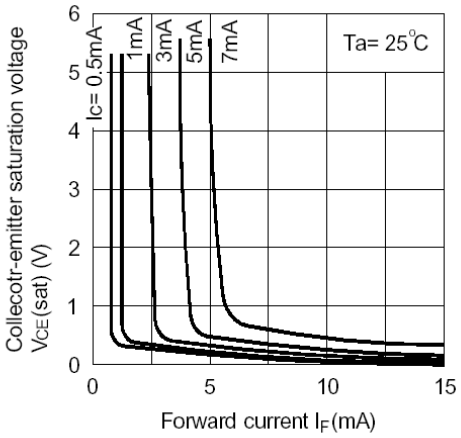


Fig.4 Forward Current vs. Forward
Voltage

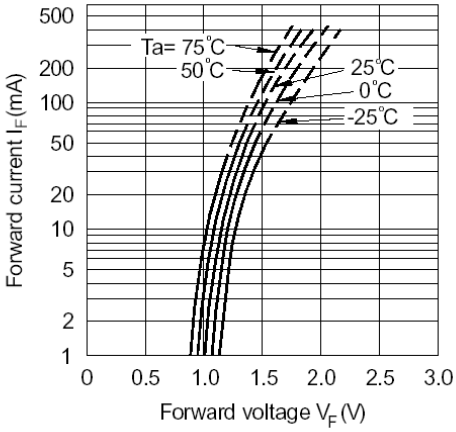


Fig.5 Current Transfer Ratio vs.
Forward Current

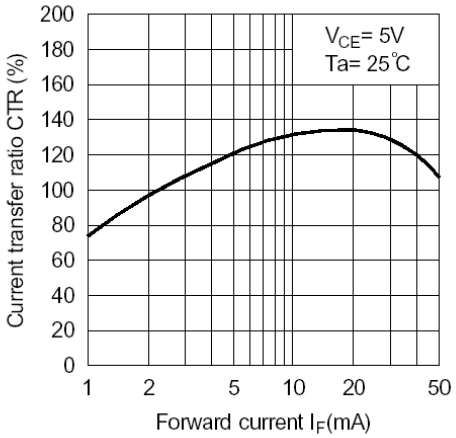
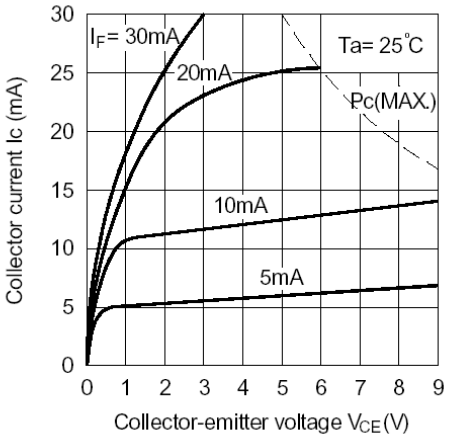


Fig.6 Collector Current vs.
Collector-emitter Voltage



●Characteristics Curves

Fig.7 Relative Current Transfer Ratio vs.Ambient Temperature

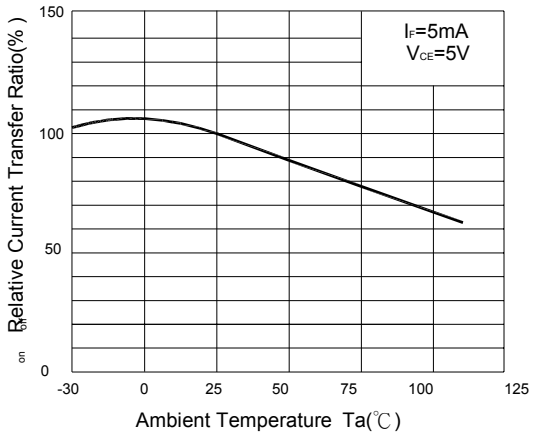


Fig.8Collector-emitter Saturation Voltage vs. Ambient Temperature

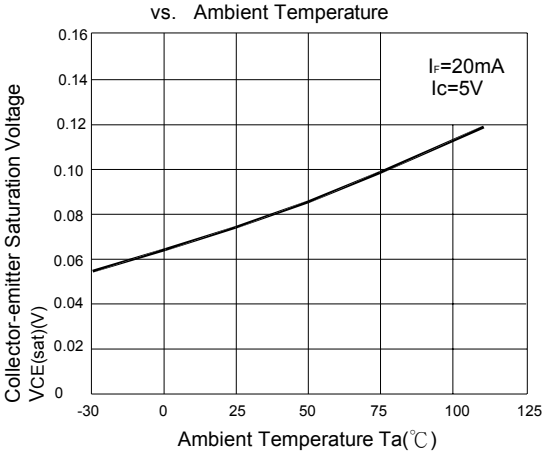


Fig.9 Collector Dark Current vs Ambient Temperature

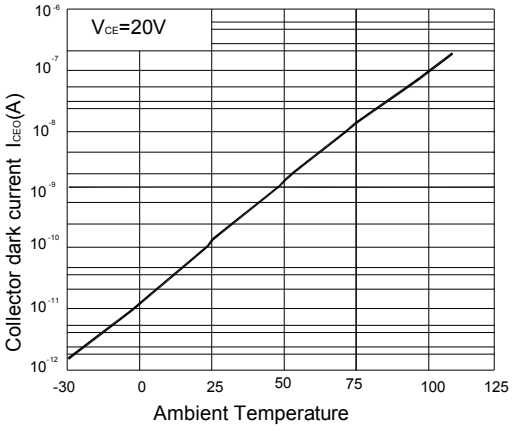


Fig.10 Response Time vs. Load Resistance

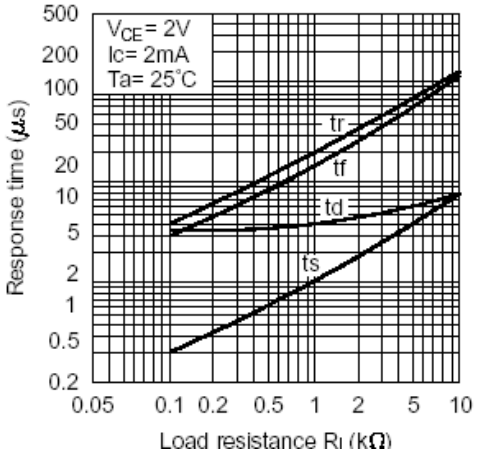
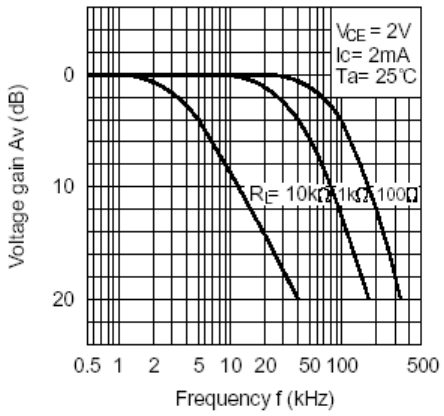
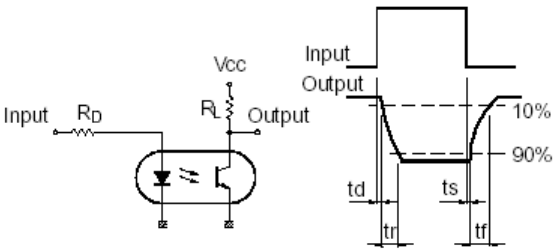


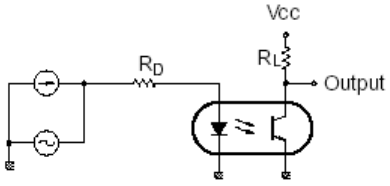
Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response



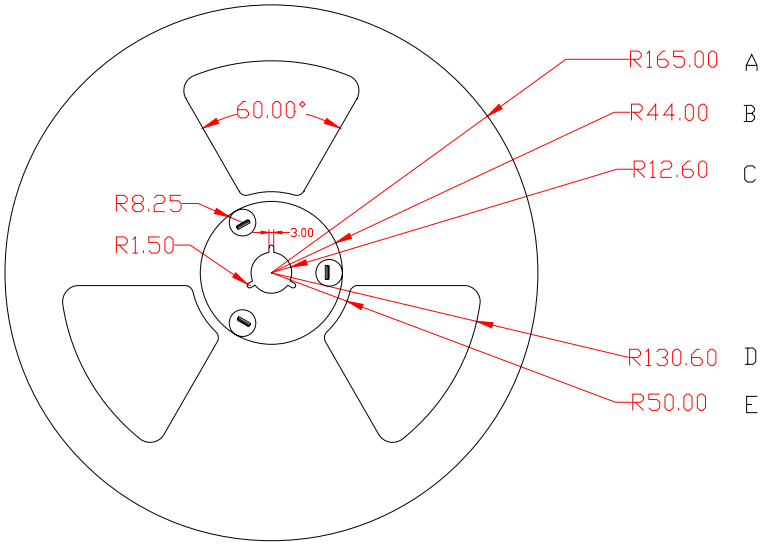
● Reliability Test

Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 :B-1	Connect with a power If=50mA Ta=Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Reverse Bias (H3TRB)	JIS C 7021 :B-11	Ta=+85℃±5℃, RH=85% PTR=V_{CE} absolute max rating*80% Test time=1000hrs	0/20
	High Temperature Reverse Bias (HTRB)	JIS C 7021 :B- 8	Ta=+105℃±5℃ PTR=V_{CE} absolute max rating Test time=1000hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS C 7021 :B-10	High Ta=+125℃±5℃ Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-55℃±5℃ Test time=1,000hrs	0/20
	Autoclave	JESD 22-A102-B	P=15PSIG, Ta=121℃ Humi. =100%RH, 48hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS C 7021 :A-4	125℃ ~ 25℃ ~ -55℃ ~ 25℃ 30min 5min 30min 5min Test Time=20cycle	0/20
	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	125℃ ~-55℃ 20min 20min Test Time=20cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS C 7021 :A-1	Operation heating： 300℃, within 10±1seconds.	0/20
	Solder Ability	MIL-S-883:2003 JIS C 7021 :A-2	Operation heating： 260℃, within 5±1seconds.	0/20

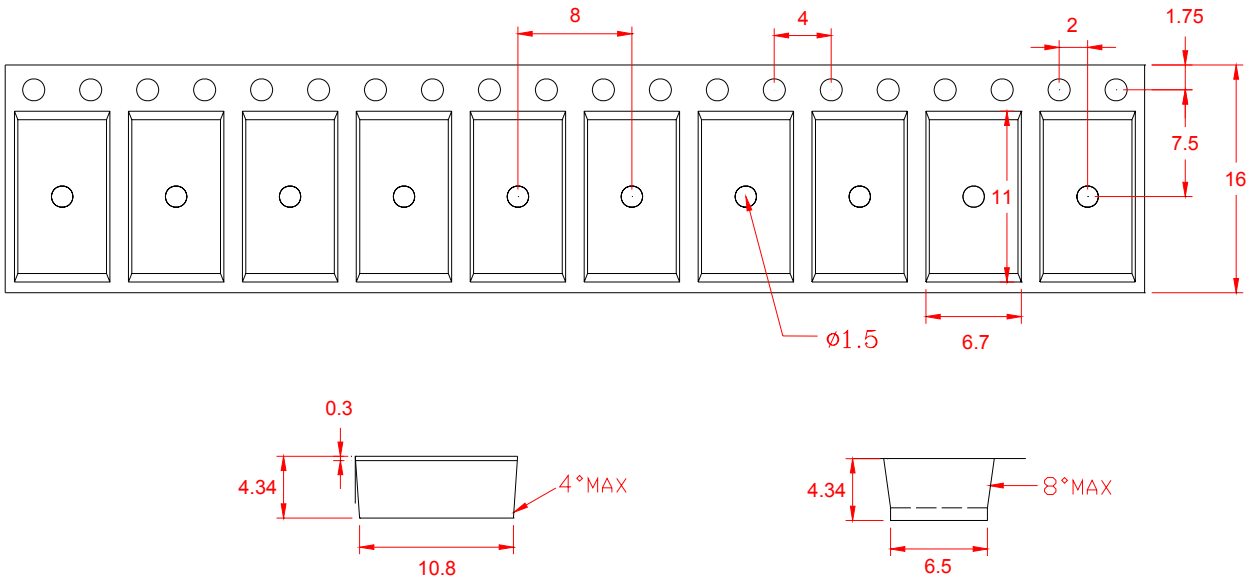
●Judgment Criteria Of Failure For The Reliability

Symbol	Measuring conditions	Judgment criteria for failure
V_F (V)	If=20mA	Over Ux1.0
Ir(uA)	Vr=6V	Over Ux1.0
CTR(%)	If=5mA, V_{CE}=5V	Shift>1.2
$V_{CE(sat)}$	I_F=20mA, I_C= 1mA	Over Ux1.0
BV_{CEO}	I_C=0.1mA, I_F=0	Over Lx1.0
BV_{ECO}	I_E=10μA, I_F=0	Over Lx1.0

● Packaging Box Dimensions (Units: mm)



● Packaging Tube Dimensions



Notes:

1、2000 PCS per reel, 10reels per Carton.

2、All dimensions are in millimeters (inches).

3. Tolerance is ±0.10mm (0.004") unless otherwise specified.

4、Specifications are subject to change without notice.